NSN 5961-00-228-6819

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-228-6819 **Inclosure Material:** Metal **Overall Length:** 0.502 inches **Overall Diameter:** 0.452 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.557 inches **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 400.0 breakover voltage, dc **Current Rating Per Characteristic:** 22.00 amperes source cutoff current **Special Features:** Internal junction configuration arrangement pnpn **Thread Series Designator:** Unf **Terminal Type And Quantity:** 3 solder stud **Specification Data:** 80131-release5169 professional/industrial association specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig:

A110a0